EPC7019D Radiation Hardened Power eGaN[®] Datasheet

Features

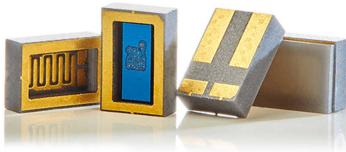
- Ultra-low Q_G For High Efficiency
- Logic Level
- Light Weight 0.160 grams
- Low R_{DS(on)}
- New Compact Hermetic Package
- Source Sense Pin
- Total Ionizing Dose LDR and HDR Immune
- Single Event Effect (SEE) Hardened
 - SEE immunity up to LET of 85 MeV/mg/cm² with $V_{\rm DS}$ up to 100% of rated Breakdown
- Neutron
 - Maintains Pre-Rad specification for up to 3 x 10¹⁵ Neutrons/cm²

Applications

- Satellite and Avionics
- Deep Space Probes
- High Speed Rad Hard DC-DC Conversion
- Rad-Hard Motor Controllers
- Nuclear Facilities

Thermal Characteristics

Symbol	Parameter-Conditions	Value	Units
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 3)	48	°C/W
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case	1.89	C/ W



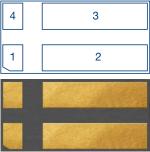
EPC7019D

Rad-Hard eGaN[®] 40 V, 80 A, 5.0 m Ω Surface Mount

Description

EPC Space FSMD-D series of eGaN[®] power switching HEMTs have been specifically designed for critical applications in the high reliability or commercial satellite space environments. These devices have exceptionally high electron mobility and a low temperature coefficient resulting in very low $R_{DS(on)}$ values. The lateral structure of the die provides for very low gate charge (Q_G) and extremely fast switching times. These features enable faster power supply switching frequencies resulting in higher power densities, higher efficiencies and more compact packaging.

Pin	Symbol	Description
1	G	Gate
2	D	Drain
3	S	Source
4	SS	Source Sense



Absolute Maximum Rating ($T_c = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter-Conditions	Value	Units
M	Drain to Source Voltage (Note 1)	40	M
V _{DS}	Drain-to-Source Voltage (up to 10,000 5 ms pulses at 150°C)	48	V
I _D	Continuous Drain Current ID @ V _{GS} = 5 V	80	
I _{DM}	Single-Pulse Drain Current t _{pulse} = 300 µs	530	A
V _{GS}	Gate to Source Voltage (Note 2)	+6 / -4	V
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	00
T _{SOL}	Package Mounting Surface Temperature	260	°C
ESD	ESD Class	1A	



Parameter	Symbol	Test Cond	ditions	MIN	ΤΥΡ	MAX	Units
Drain to Source Voltage	B _{VDSS}	$V_{GS} = 0 V, I_{D} = 1 mA$		40			V
Drain to Source Leakage	1	V _{DS} = 40 V	$T_{\rm C} = 25^{\circ}{\rm C}$		0.001	0.4	
	DSS	$V_{GS} = 0 V$	T _C = 125°C		0.01		-
Gate to Source Forward Leakage		$V_{GS} = 5 V$	T _C = 25°C		0.05	1.0	mA
Gate to Source Forward Leakage [#]	I _{GSS}	V _{GS} = 5 V	T _C = 125°C		0.2	4.0	_
Gate to Source Reverse Leakage		$V_{GS} = -4 V$	T _C = 25°C		0.05	1.0	
Gate to Source Threshold Voltage	V _{GS(th)}		T _C = 25°C	0.8	1.4	2.5	V
Gate to Source Threshold Voltage Temperature Coefficient	$\Delta V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 18 \text{ mA}$	-55°C < T _A < 150°C		-2.0		mV/°C
Drain to Source Resistance (Note 4)	R _{DS(on)}	$V_{GS} = 5 \text{ V}, \text{ I}_{D} = 50 \text{ A}$	T _C = 25°C		3.7	5.0	mΩ
Source to Drain Forward Voltage (Note 5)	V _{SD}	$I_{\rm S} = 0.5 \text{ A}, V_{\rm G} = 0 \text{ V}$	T _C = 25°C		2.0		V

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Static Characteristics (Typical (TYP) values are for reference only.)

All measurements were done with substrate shorted to source.

Defined by design. Not subject to production test.

Dynamic Characteristics ($T_c = 25^{\circ}C$ unless otherwise noted. Typical (TYP) values are for reference only.)

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Parameter	Symbol	Test Conditions	MIN	ΤΥΡ	MAX	Units
Input Capacitance	C _{ISS}			2830		
Reverse transfer Capacitance	C _{RSS}	$V_{DS} = 20$ V, $V_{GS} = 0$ V		35		
Output Capacitance	C _{OSS}			1660		pF
Effective Output Capacitance, Energy Related	C _{OSS(ER)}			2130		-
Effective Output Capacitance, Time Related	C _{OSS(TR)}	$V_{DS} = 0$ to 20 V, $V_{GS} = 0$ V		2540		
Total Gate Charge	Q _G	$V_{\rm DS}$ = 0 to 20 V, $V_{\rm GS}$ = 0 V, $I_{\rm D}$ = 50 A		22		
Gate to Source Charge	Q _{GS}			9.1		
Gate to Drain Charge	Q _{GD}	$V_{DS} = 20$ V, $I_{D} = 50$ A		3.4		nC
Output Charge (Note 6)	Q _{OSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$		51		
Source to Drain Recovery Charge	Q _{RR}			0		1

All measurements were done with substrate shorted to source.

Radiation Characteristics

EPC Space eGaN[®] HEMTs are tested according to MIL-STD-750 Method 1019 for total ionizing dose validation. Every manufacturing lot is tested for total ionizing dose of Gamma radiation with an in-situ bias for (i) $V_{GS} = 5 V$, (ii) $V_{DS} = V_{GS} = 0 V$ and (iii) $V_{DS} = 80\% B_{VDSS}$.

Parameter	Symbol	Test Conditions	MIN	ТҮР	MAX	Units
Maximum Drain to Source Voltage	V _{DSMAX}	$V_{GS} = 0 V, I_{D} = 1 mA$	40			N
Gate to Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 18 \text{ mA}$	0.8	1.4	2.5	V
Drain to Source Leakage	I _{DSS}	$V_{DS} = 40$ V, $V_{GS} = 0$ V		0.001	0.4	
Gate to Source Forward Leakage		$V_{GS} = 5 V$		0.05	1.0	mA
Gate to Source Reverse Leakage	IGSS	$V_{GS} = -4 V$		0.05	1.0	
Drain to Source Resistance (Note 4)	R _{DS(on)}	I _D = 50 A, V _{GS} = 5 V		3.7	5.0	mΩ

Electrical Characteristics up to 1000 krads (*T_c* = 25°C unless otherwise noted. Typical (TYP) values are for reference only.)

Typical Single Event Effect Safe Operating Area

Note : All Single Event Effect testing is performed on the K-500 Cyclotron at Texas A&M University

Test	Environment				V _{DS} Vol	tage (V)
	lon	LET MeV/mg/cm ²	Range µm	Energy MeV	$V_{GS} = 0 V$	$V_{GS} = -4V$
See SOA	Xe	50	131	1653	40	40
	Au	83.7	130	2482	40	40

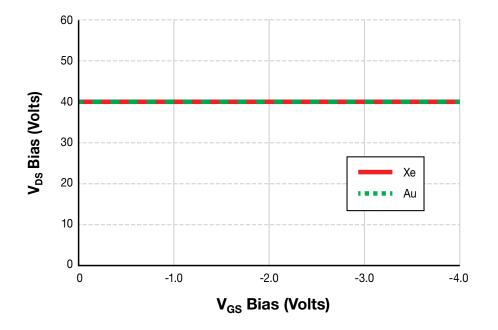


Figure 1: Typical Single Event Effect Safe Operating Area

Figure 3: Typical Output Characteristics at 125°C

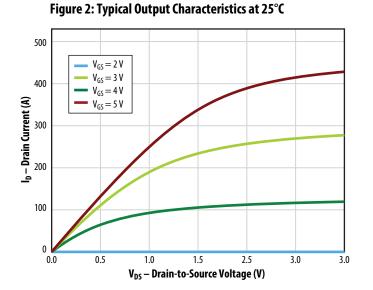
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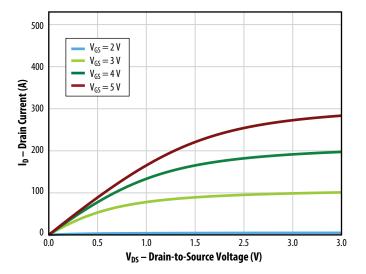


Figure 4: Typical Transfer Characteristics

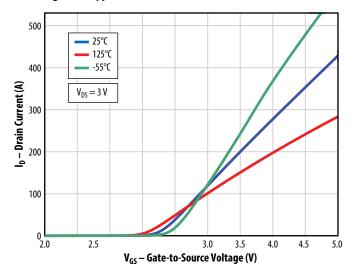
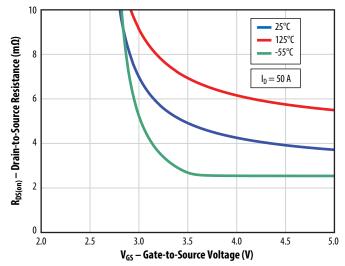
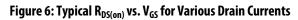
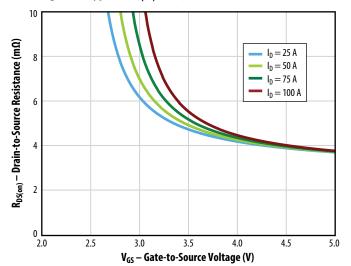
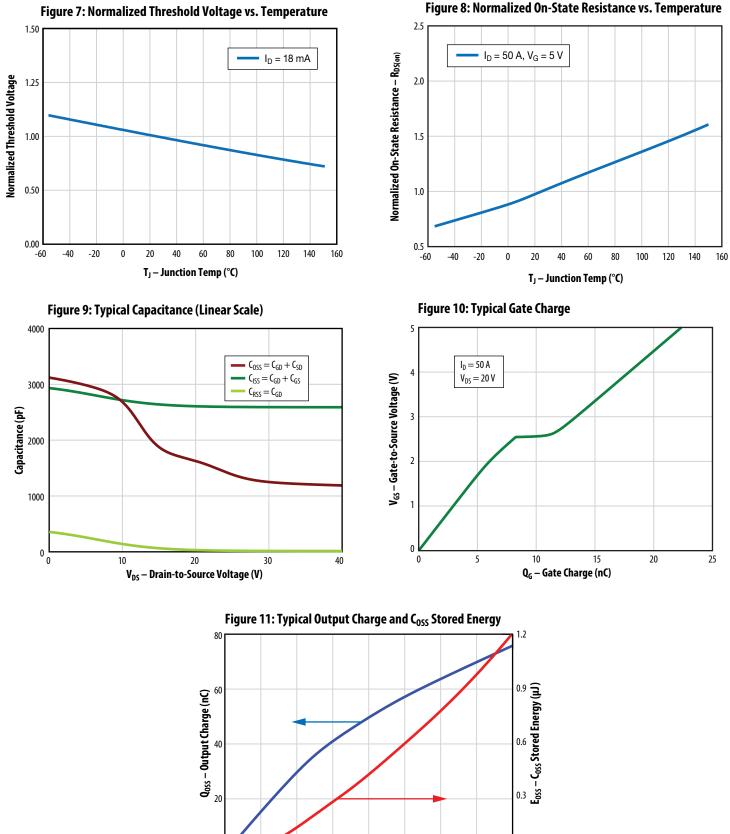


Figure 5: Typical R_{DS(on)} vs. V_{GS} for Various Temperatures









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V_{DS} – Drain-to-Source Voltage (V)

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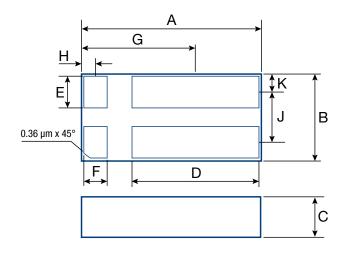
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Package Outline and Dimensions



Symbol	Inches		Inches Millimeters		Note
Cynisor	MIN	MAX	MIN	MAX	
Α	0.311	0.321	7.90	8.15	
В	0.177	0.187	4.50	4.75	
С	0.078	0.088	1.98	2.24	
D	0.222	0.232	5.64	5.89	
Е	0.065	0.075	1.65	1.91	
F	0.045	0.055	1.14	1.40	
G	0.195	0.205	4.95	5.21	
н	0.025	0.035	0.64	0.89	
К	0.035	0.045	0.89	1.14	
J	0.095	0.105	2.41	2.67	

Standard Terminal Pad finish is a solder alloy of 63%Pb 37%Sn

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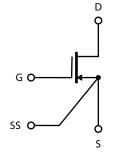
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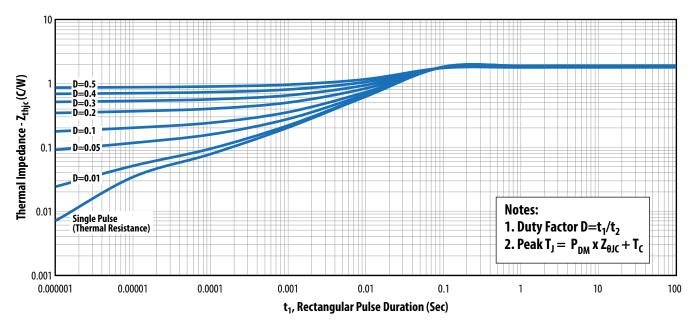
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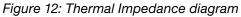
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Package Connections



NOTE: SS pin is connected directly to source of internal die.

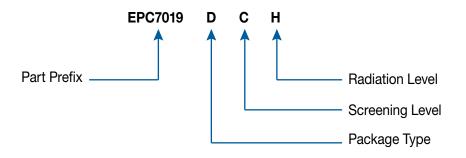




Notes

- Note 1. NEVER exceed the absolute maximum V_{DS} of the device otherwise permanent damage/destruction may result.
- Note 2. NEVER exceed the absolute maximum V_{GS} of the device otherwise permanent damage/destruction may result. We recommend a V_{GS} of 5 V for optimum operation across life and radiation.
- Note 3. R_{0JA} measured with FSMD-D package mounted to double-sided PCB, 0.063" thickness with 1.0 square inches of copper area on the top (mounting side) and a flood etch (3 square inches) on the bottom side.
- Note 4. Measured using four wire (Kelvin) sensing and pulse measurement techniques. Measurement pulse width is 80 µs and duty cycle is 1%, maximum.
- Note 5. With pulse measurement width 100–380 $\mu s.$
- Note 6. Guaranteed by design/device construction. Not tested.

EPC Space Part Number Information



Ordering Information Availability

Screening Options	Rad Assurance Options
1 character	1 character
C or Q = Developmental Units S = Space Level ¹	H = 1000 krad

Part Number	Screening Level	Shipping
EPC7019DC	Developmental Units	Moffle trave
EPC7019DSH	Space Level	Waffle trays

¹ Screening and qualification consistent to an equivalent MIL-PRF-19500 specification.

EPC7019DC devices are intended for engineering development purposes only and are NOT intended to be used as flight units.

EPC Space Rad Hard HEMT are not sensitive to Total Ionizing Dose as such the H level covers the R,F,G radiation levels.

Screening Flow Equivalent to a MIL-PRF-19500 General Specification

	EPC SPACE Qual Flow Equivalen	t to a MIL-PRF-19500 Spec	ification			
Operation	Test	Test Methods Per Mil STD 750	Sample Size	Space Level	СОТ	
	Probe Testing	EPC SPACE Internal	100%	✓	✓	
Pre-Assembly	Visual inspection	EPC SPACE Internal	100%	\checkmark	✓	
Deet Assembly	Die Shear	2,017	5	✓	√	
Post-Assembly	X-Ray	2076	5	✓	✓	
	Serilialization		100%	✓		
	Electricals	3411,3413,3421,3404	100%	✓	✓	
	Temp Cycling	1051	100%	✓		
	Constant Acceleration	2006	100%	✓		
	PIND	2052	100%	\checkmark		
	Initial Electricals (Read and Record)	3411,3413,3421,3404	100%	\checkmark		
	HTGB	1042 Condition B	100%	✓		
Screening	Interim Electricals (Read and Record)	3411,3413,3421,3404	100%	✓		
	HTRB	1042 Condition A 240 Hours	100%	✓		
	Final Electricals (Read and Record)	3411,3413,3421,3404	100%	✓		
	Final Electricals (High and Low Temperatures)	3411,3413,3421,3404	100%	\checkmark		
	Deltas	Per Procurement Specification	100%	✓		
	Percent Defective Allowable	Per Procurement Specification	100%	✓		
	Dynamic RDSON	EPC SPACE Internal	100%	✓		
	OutLiers Removal	EPC SPACE Internal	100%	✓		
	X-RAY	2076	100%	✓		
	Tinning		100%	✓		
	Hermetic Seal, Fine & Gross Leak	1071	100%	✓		
	Final Electricals	3411,3413,3421,3404	100%	✓		
	A-2 DC Static Tests at 25°C	3411,3413,3421,3404	116	\checkmark		
Group A Inspection	A-3 High & Low Temp DC Static Tests	3411,3413,3421,3404	116	\checkmark		
(Conformance)	A-7 Gate Charges	3471 Condition B	45	✓		
	A-7 Capacitance	3473	45	\checkmark		
Group B Inspection (Conformance)	B-1, B-2, B-3, B-4, B-5	Sample base equivalent to a M procureme	IL-PRF-19500 flo nt specificcation	•	d by	
Group C Inspection (Conformance)	C-1, C-2, C-3, C-4, C-6, C-7	Sample base performed yearly per package style equivalent to a MIL-PRF-19500 flow or as required by procurement specification				
Group D Inspection	TID	1019	15	✓		
Conformance)	SEE	1080	5	✓		
Group E Inspection (Qualification	E-1, E-2, E-5, E-6 E-7	Performed during product intro equivalent to a MIL-PRF			nge	
Inspection)	E8 Switching	procurement specification				

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Revisions

Datasheet Revision	Product Status
REV Q1	Characterization and Qualification
Preliminary	Production Released

Information subject to change without notice. Revised October, 2023